## Flip Chip PIN Diode

#### **Features**

- Low Series Resistance
- Low Capacitance
- Fast Switching Speed
- Silicon Nitride Passivation
- Polymer Scratch Protection
- RoHS Compliant

#### Description

M/A-COM Technology Solutions MA4FCP200 is a silicon flip chip PIN diode fabricated using a patented HMIC process which provides for repeatable electrical characteristics. This diode is fabricated on epitaxial wafers using a process designed for extremely low parasitics. The diode is fully passivated with silicon nitride to minimize leakage current. The chip also has an additional polymer layer for impact and scratch protection to prevent damage to the active area during handling.

#### Applications

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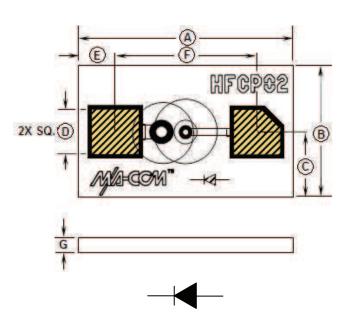
The small outline and low 0.05pS RC product, make the device useful in multi-throw switches and switched phase shifter circuits requiring <20nS switching speeds at operating frequencies up to 18GHz.

## Absolute Maximum Ratings<sup>1</sup> T<sub>AMB</sub> = +25°C (unless otherwise specified)

Parameter	Absolute Maximum		
Forward Current	100mA		
Reverse Voltage	- 70V		
Operating Temperature	- 55°C to + 125°C		
Storage Temperature	- 55°C to + 150°C		
Dissipated Power RF plus DC	100mW		
Mounting Temperature	+300°C for 10 seconds		

1. Exceeding any of these limits may cause permanent damage to the chip.





1264 Outline

- Backside metal contacts: 0.1µM thick gold.
- Yellow hatched areas indicate backside, mounting, ohmic, gold contacts.

Dim	Inch	nes	Millimeters		
Dim.	Min.	Max.	Min.	Max.	
А	0.014	0.015	0.356	0.381	
В	0.008	0.009	0.203	0.229	
С	0.004	0.005	0.102	0.127	
D	0.003	0.004	0.076	0.102	
Е	0.002	0.003	0.175	0.225	
F	0.008	0.010	0.203	0.254	
G	0.004	0.006	0.102	0.152	

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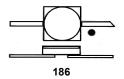
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Parameters @ Conditions	Symbol	Units	Min.	Тур.	Max.
Total Capacitance @ -40V, 1MHz <sup>1</sup>	CT	pF		0.025	0.030
Total Capacitance @ -40V, 1GHz <sup>1,3</sup>	CT	pF		0.020	
Series Resistance @ +50mA <sup>2,3</sup> , 100MHz	Rs	Ω		2.4	3.0
Series Resistance @ +50mA <sup>2,3</sup> , 1GHz	Rs	Ω		2.8	
Forward Voltage @ +100mA	V <sub>F</sub>	V		1.25	1.5
Reverse Voltage @ -10µA	V <sub>R</sub>	V	70		
Reverse Current @ -70V	I <sub>R</sub>	μΑ			10
Lifetime @ $I_F$ = +10mA / $I_{REV}$ = -6mA	TL	nS		100	
Steady State Thermal Resistance <sup>4</sup>	θ	°C/W		900	

## Electrical Specifications @ T<sub>AMB</sub> +25°C

- 1. Total capacitance is equivalent to the sum of junction capacitance, Cj, plus the die parasitic capacitance, Cp.
- 2. The series resistance, R<sub>S</sub> is equal to the total diode resistance which also includes the resistance of the junction, Rj.
- 3. Rs and Cp measured on an HP4291A with die mounted in an ODS-186 package.
- 4. Steady-state Thermal Resistance measured with die mounted in an ODS-186 package.



#### ESD

These devices very susceptible to ESD and are rated Class 0 (0-199V) per HBM MIL-STD-883, method 3015.7 [C = 100pF  $\pm$ 10%, R = 1.5kW  $\pm$ 1%]. Even though die survived ESD testing to 100V, they should be handled in a static free environment.

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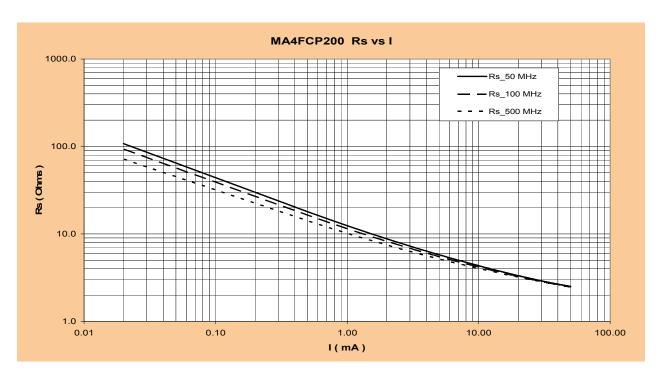
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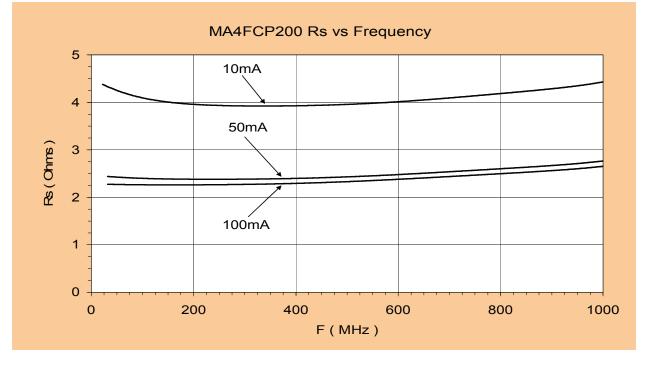


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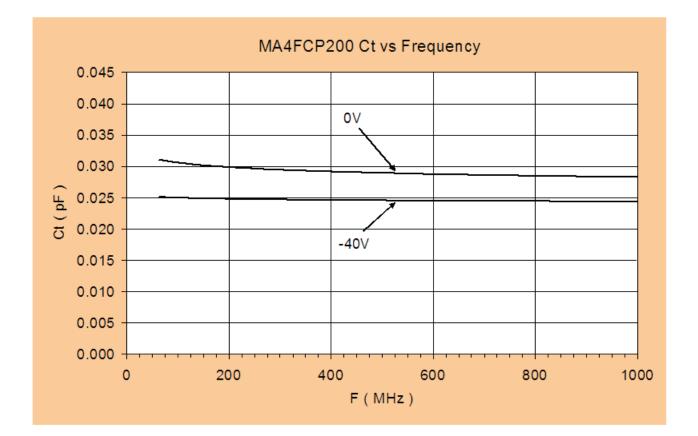
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### Typical Performance @ T<sub>AMB</sub> +25°C



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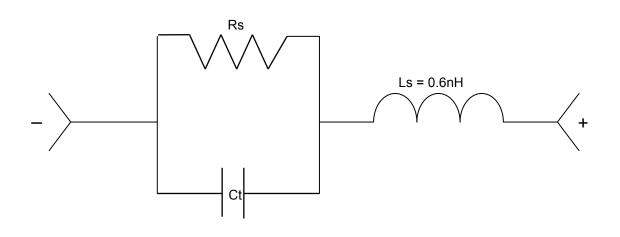
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## MA4FCP200 SPICE Model

**PinDiodeModel** NLPINM1 Is=1.0E-14 A wBv = 70 VVi=0.0 V wPmax= 100 mW Un= 900 cm^2/V-sec Ffe=1.0Wi= 5.0 um Rr= 10 K Ohms Cimin= 0.02 pF Tau= 0.10 usec Rs(I) = Rc + Ri(I) = 0.05 Ohm + Ri(I)Cj0= 0.03 pF Vj= 0.7 V M = 0.5Fc = 0.5Imax= 1.0 E+5 A/m^2 Kf=0.0 Af=1.0



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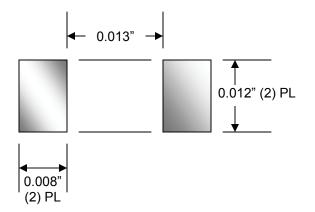
#### **Handling Procedures**

All semiconductor chips should be handled with care to avoid damage or contamination from perspiration and skin oils. The use of plastic tipped tweezers or vacuum pickups is strongly recommended for individual components. Bulk handling should insure that abrasion and mechanical shock are minimized.

#### **Bonding Techniques**

These devices were designed for insertion onto hard or soft substrates with the junction (pad) side down. They can be mounted with electrically conductive epoxy or with a eutectic solder preform. However, tin rich solders will scavenge gold from the bottom contacts and are not recommended. Indalloy or 80/20, Au/Sn, solders are acceptable. Maximum soldering temperature must be <300°C for <10 sec. These chips are designed to be inserted onto hard or soft substrates with the junction side down. They should be mounted onto silk-screened circuits using electrically conductive Ag epoxy, approximately 1-2 mils in thickness and cured at approximately 90°C to 150°C per manufacturer's schedule. For extended cure times, >30 minutes, temperatures must be kept below 200°C. The die can also be assembled using non conductive epoxy with the junction side up, and wire or ribbon bonds made to the pads.





#### **Ordering Information**

Part Number	Packaging
MA4FCP200	Die in Gel Pack
MA4FCP200-W	Wafer Cut on Tape

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